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## **ELECTRONIC INFORMATION DISCLOSURE STATEMENT**

Electronic Version v18

Stylesheet Version v18.0

Title of Invention

METHOD FOR CREATING A SELF-ALIGNED SOI DIODE BY REMOVING A POLYSILICON GATE DURING PROCESSING

Application Number:

10/708912

2911

Confirmation Number: First Named Applicant:

Kiran Chatty

Attorney Docket Number:

BUR920030180US1

Art Unit:

Examiner:

Search string:

( 5629544 or 5811857 or 6232163 or 6245600 or 6589823 or 6576958 or 6590264

or 20020119608 or 20030080386 ).pn

## **US Patent Documents**

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
759	1	5629544	1997-05-13	Voldman, et al			
1	2	5811857	1998-09-22	Assaderaghi, et al			
	3	6232163	2001-05-15	Voldman, et al			
	4	6245600	2001-06-12	Geissler, et al			
	5	6589823	2003-07-08	Beebe, et al			
]/	6	6576958	2003-06-10	Ker, et al		/	
738	7	6590264	2003-07-08	Ker, et al	l		

## **US Published Applications**

Note: Applicant is not required to submit a paper copy of cited US Published Applications

init	Cite.No.	Pub. No.	Date	Applicant	Kind	Class	Subclass
73	1	20020119608	2002-08-29	Ko, et al			
TSR	2	20030080386	2003-05-01	Ker, et al			

## Signature

Examiner Name	Date	
	12/11/05	